

## Product Overview

### NSBA123TF3: PNP Bipolar Digital Transistor (BRT)

For complete documentation, see the data sheet.

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are PbFree, Halogen Free/BFR Free and are RoHS Compliant

### Part Electrical Specifications

Product	Compliance	Status	Polarity	$I_C$ Continuous (A)	$V_{BRICE0}$ Min (V)	$h_{FE}$ Min	R1 (k $\Omega$ )	R2 (k $\Omega$ )	R1/R2 Typ	$V_{i(off)}$ Max (V)	$V_{i(on)}$ Min (V)	Package Type
NSBA123TF3T5G	Pb-free Halide free	Active	PNP	0.1	50	160	2.2	Infinity	-	0.5	1.3	SOT-1123-3

For more information please contact your local sales support at [www.onsemi.com](http://www.onsemi.com).

Created on: 5/19/2019